

AMENDMENTS TO THE SPECIFICATION

Please amend the paragraph beginning at page 1, line 19, as follows:

The GMR device has a sandwich-structured laminate film including a ferromagnetic metal layer, a ~~ferromagnetic~~ nonmagnetic metal layer and a ferromagnetic metal layer. The laminate film is often referred to as a "spin valve film". In this spin valve film, one ferromagnetic metal layer has a substantially pinned magnetization, which is fixed by a ferromagnetic coupling bias applied thereto by an exchange coupling between the ferromagnetic metal layer and an antiferromagnetic metal layer formed adjacent to the ferromagnetic metal layer. The magnetization pinned layer of ferromagnetic metal material may be referred to as "a magnetization pinned layer", while another ferromagnetic metal layer has a magnetization free to rotate in an applied magnetic field (usually signal magnetic field) is usually referred to as "a magnetization free layer".